



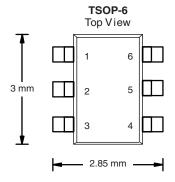
P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}$ (Ω)	I _D (A)		
- 20	0.042 at V _{GS} = - 4.5 V	- 5.6		
	0.057 at V _{GS} = - 2.5 V	- 4.8		
	0.080 at V _{GS} = - 1.8 V	- 4.1		

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFETs: 1.8 V Rated
- Compliant to RoHS Directive 2002/95/EC

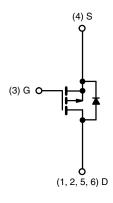




Ordering Information: Si3433BDV-T1-E3 (Lead (Pb)-free)

Si3433BDV-T1-GE3 (Lead (Pb)-free and Halogen-free)

Marking Code: B3xxx



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 20		V	
Gate-Source Voltage		V _{GS}	± 8			
Continuous Dunis Comment /T 450 0008	T _A = 25 °C	- I _D	- 5.6	- 4.3		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		- 4.1	- 3.1		
Pulsed Drain Current		I _{DM}	- 20		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	- 1.7	- 0.9	<u> </u>	
M	T _A = 25 °C	P _D 2.0 1.0	2.0	1.1	W	
Maximum Power Dissipation ^a	T _A = 85 °C		0.6	VV		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana de la Arabia da	t ≤ 5 s	- R _{thJA}	50	60	
Maximum Junction-to-Ambient ^a	Steady State		90	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	35	42	

Notes

a. Surface Mounted on 1" x 1" FR4 board.

Vishay Siliconix



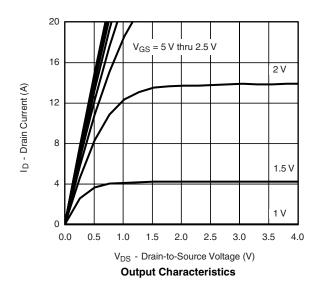
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit	
Static			<u> </u>				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.45		- 0.85	V	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V			± 100	nA	
Zero Gate Voltage Drain Current		V _{DS} = - 20 V, V _{GS} = 0 V			- 1	- 1 - 5 μA	
	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 85 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 20			Α	
Drain-Source On-State Resistance ^a		V _{GS} = - 4.5 V, I _D = - 5.6 A		0.034	0.042	Ω	
	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 4.8 A		0.045	0.057		
		V _{GS} = - 1.8 V, I _D = - 1 A		0.060	0.080		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 5.6 A		10		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.7	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			12	18		
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -5.6 \text{ A}$		1.7		nC	
Gate-Drain Charge	Q_{gd}			3.5			
Turn-On Delay Time	t _{d(on)}			15	25		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		45	75	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		80	130		
Fall Time	t _f			60	100		
Source-Drain Reverse Recovery Time t		I _F = - 1.7 A, dl/dt = 100 A/μs		40	70		

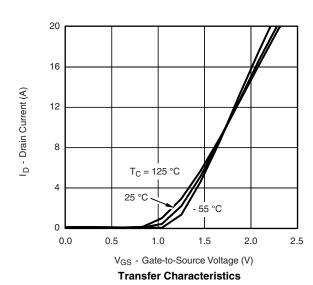
Notes:

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



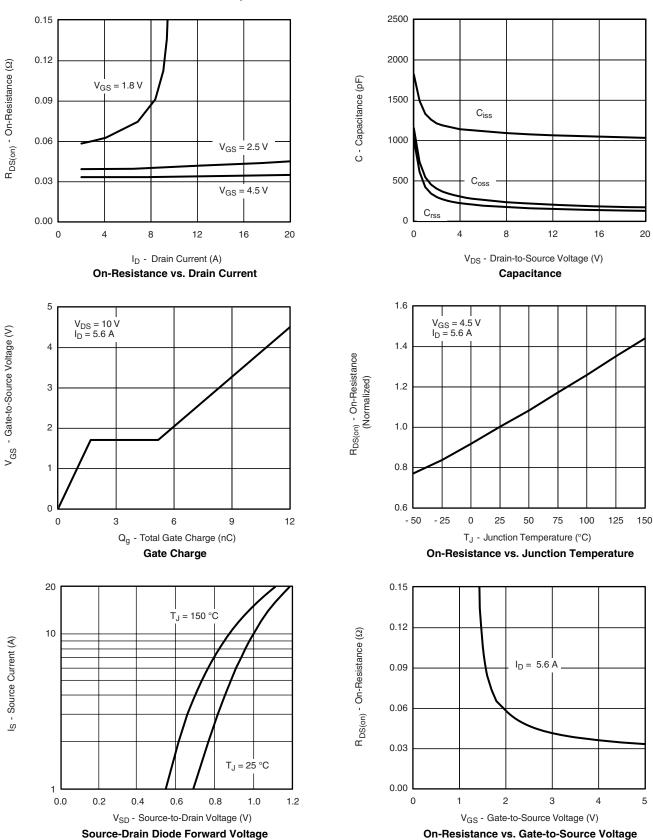








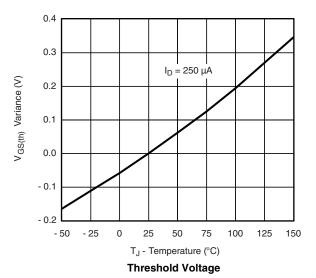
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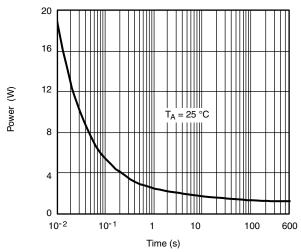


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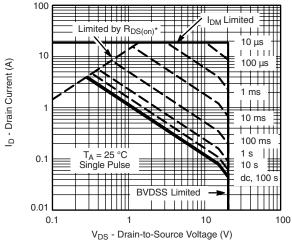
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



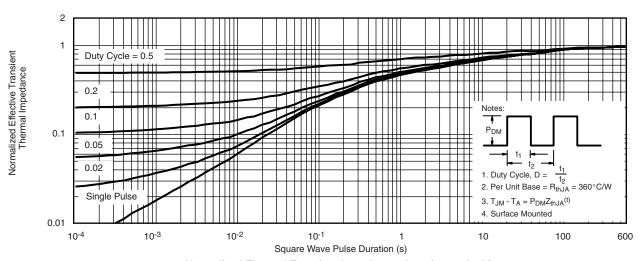


Single Pulse Power



* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

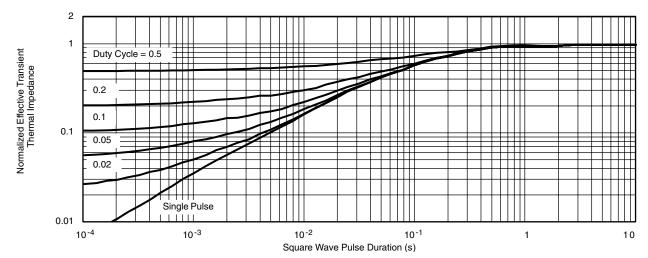
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

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